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September 2001

FDS6575

P-Channel 2.5V Specified PowerTrench[®] MOSFET

General Description

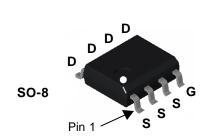
This PChannel 2.5V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 8V).

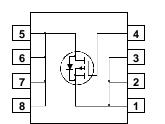
Applications

- Power management
- Load switch
- Battery protection

Features

- -10 A, -20 V. $R_{DS(ON)}$ = 13 m Ω @ V_{GS} = -4.5 V $R_{DS(ON)}$ = 17 m Ω @ V_{GS} = -2.5 V
- Low gate charge
- + High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High current and power handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-20	V
V _{GSS}	Gate-Source Voltage		±8	V
l _D	Drain Current – Continuous	(Note 1a)	-10	A
	– Pulsed		-50	
PD	Power Dissipation for Single Operation	(Note 1a)	2.5	W
		(Note 1b)	1.5	
		(Note 1c)	1.2	
T_J, T_{STG}	Operating and Storage Junction Temperate	ure Range	-55 to +175	°C
Therma	I Characteristics	·		
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W
R _{0JA}	Thermal Resistance, Junction-to-Ambient	(Note 1c)	125	°C/W
R _{0JC}	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS6575	FDS6575	13"	12mm	2500 units

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FDS6575

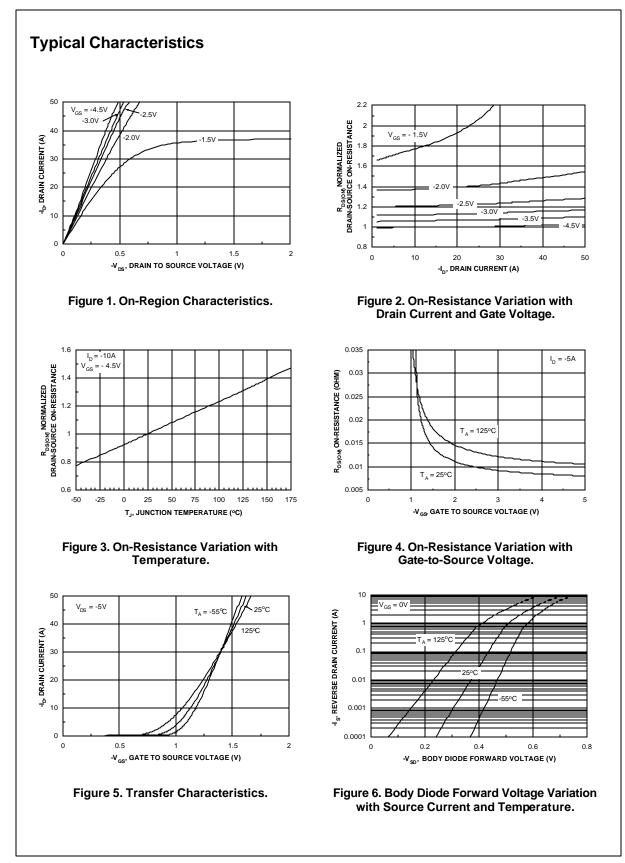
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = -250 \mu A$	-20			V
$\Delta BV_{DSS} \Delta T_{J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-13		mV/ºC
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -16 V$, $V_{GS} = 0 V$			-1	μA
GSSF	Gate-Body Leakage, Forward	$V_{GS} = 8 V$, $V_{DS} = 0 V$			100	nA
GSSR	Gate-Body Leakage, Reverse	$V_{GS} = -8 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \mu A$	-0.4	-0.6	-1.5	V
$\Delta V_{GS(th)} \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		3		mV/ºC
R _{DS(on)}	Static Drain–Source	$V_{GS} = -4.5 \text{ V}, I_D = -10 \text{ A}$		8.5	13	mΩ
	On–Resistance	$V_{GS} = -2.5 V, I_D = -9 A$		11	17	
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -10 \text{ A}, \text{ T}_{J} = 125^{\circ}\text{C}$		11	20	
D(on)	On–State Drain Current	$V_{GS} = -4.5 V, V_{DS} = -5 V$	-50			A
g fs	Forward Transconductance	$V_{DS} = -5 V$, $I_D = -10 A$		57		S
Dynamic	Characteristics		-			
Ciss	Input Capacitance	$V_{DS} = -10 V$, $V_{GS} = 0 V$,		4951		pF
Coss	Output Capacitance	f = 1.0 MHz		884		pF
Crss	Reverse Transfer Capacitance			451		pF
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -10V, \qquad I_D = -1 A,$		16	29	ns
tr	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, R_{GEN} = 6 \Omega$		9	18	ns
t _{d(off)}	Turn–Off Delay Time			196	314	ns
t _f	Turn–Off Fall Time			78	125	ns
Qg	Total Gate Charge	$V_{DS} = -10 V$, $I_D = -10 A$,		53	74	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 V$		6		nC
Q _{gd}	Gate–Drain Charge			12		nC
Drain-Se	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain–Source	Diode Forward Current			-2.1	А
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \ V, \ I_S = -2.1 \ A$ (Note 2)		-0.6	-1.2	V
	of the junction-to-case and case-to-ambient thermal r R _{0JC} is guaranteed by design while R _{0CA} is determine a) 50 °C/W when mounted on a 1in ²	d by the user's board design.			vhen mounte	

Scale 1 : 1 on letter size paper

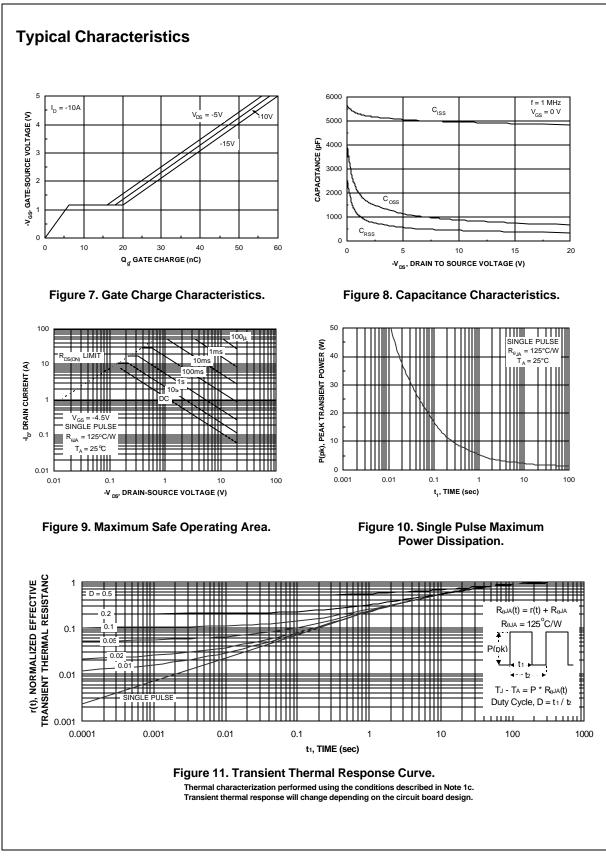
669e

2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%

FDS6575 Rev F(W)



FDS6575



FDS6575

FDS6575 Rev F(W)

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